

# **RDS60A-48**

## **EVALUATION DATA**

### **型式データ**

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## 使用記号 Terminology used

## 定義 Definition

Vin	.....	入力電圧	Input voltage
Vout	.....	出力電圧	Output voltage
Iin	.....	入力電流	Input current
Iout	.....	出力電流	Output current
Ta	.....	周囲温度	Ambient temperature
f	.....	周波数	Frequency
RC	.....	ON／OFFコントロール	ON/OFF Control

※ 当社測定条件における結果であり、参考値としてお考え願います。

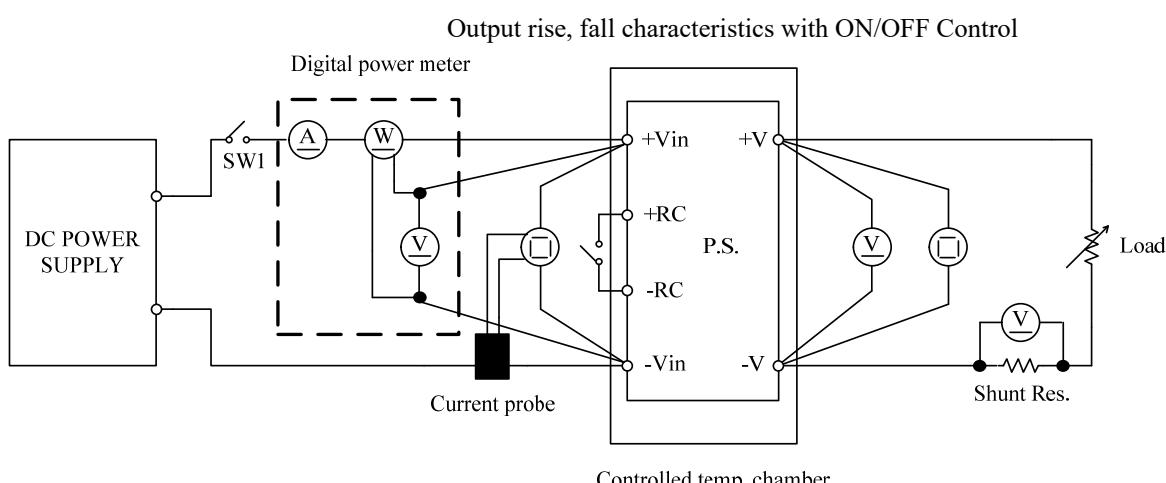
Test results are reference data based on our measurement condition.

## 1. 測定方法 Evaluation Method

### 1-1. 測定回路 Circuit used for determination

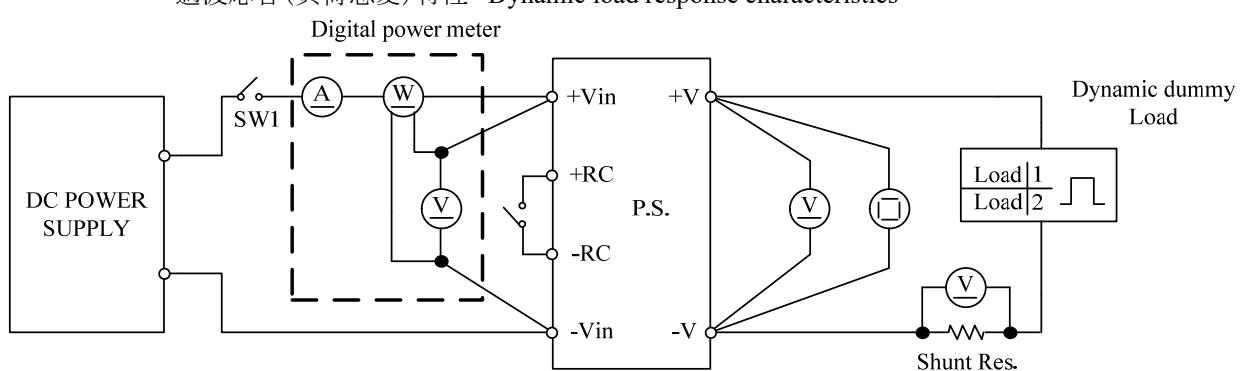
測定回路1 Circuit 1 used for determination

- 静特性 Steady state data
- 通電ドリフト特性 Warm up voltage drift characteristics
- 出力保持時間特性 Hold up time characteristics
- 出力立ち上がり特性 Output rise characteristics
- 出力立ち下がり特性 Output fall characteristics
- 過電流保護特性 Over current protection (OCP) characteristics
- 過電圧保護特性 Over voltage protection (OVP) characteristics
- 入力電流波形 Input current waveform
- ON/OFFコントロール時出力立ち上がり、立下がり特性 Output rise, fall characteristics with ON/OFF Control

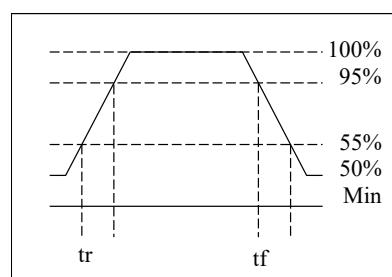


測定回路2 Circuit 2 used for determination

- 過渡応答(負荷急変)特性 Dynamic load response characteristics

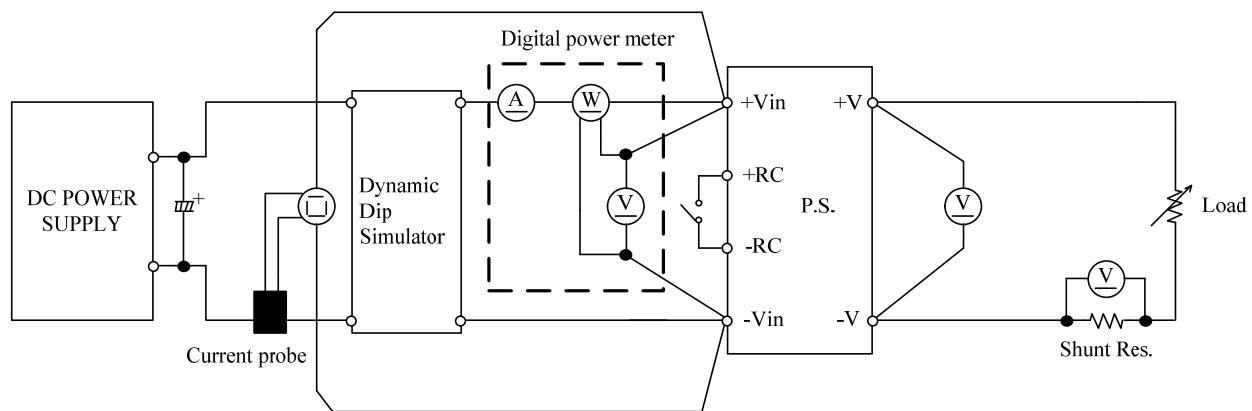


Output current waveform  
 $I_{out} 50\% \leftrightarrow 100\%$

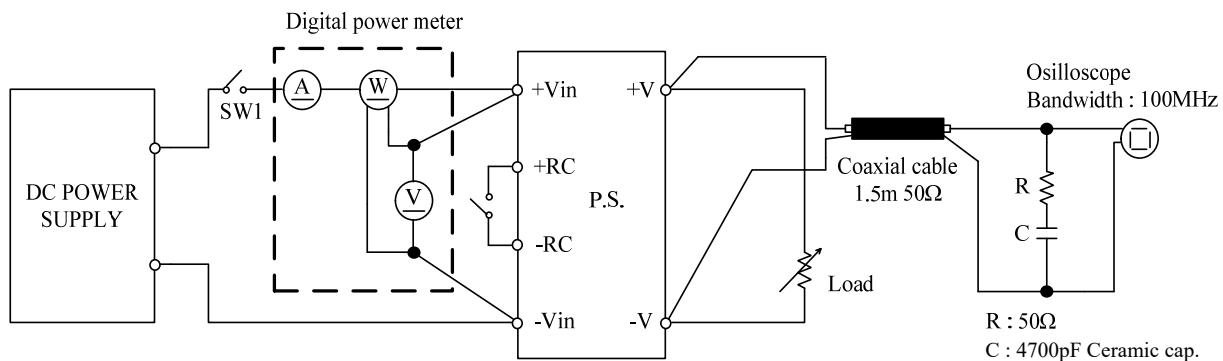


測定回路3 Circuit 3 used for determination

- 入力サージ電流（突入電流）波形 Inrush current waveform

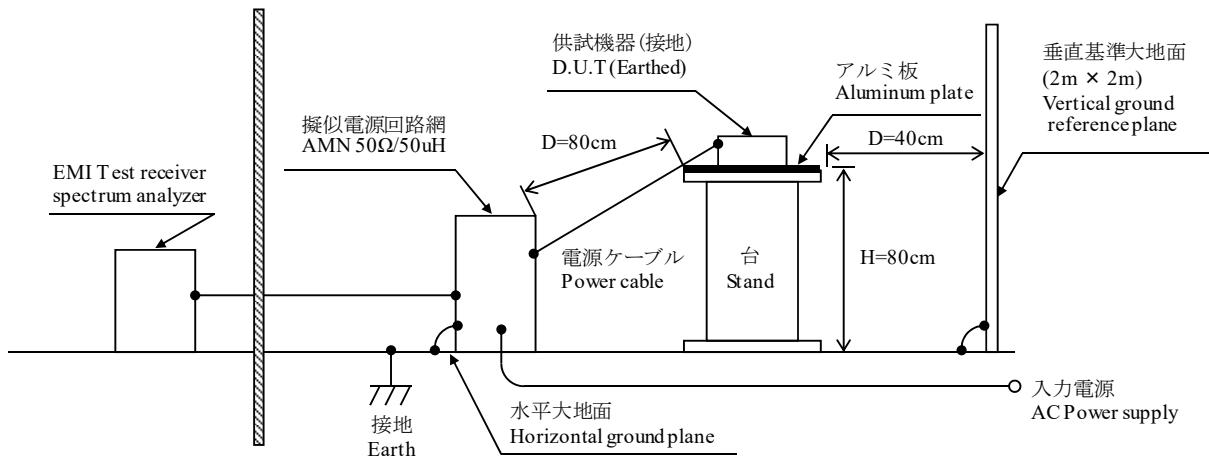
測定回路4 Circuit 4 used for determination

- 出力リップル、ノイズ波形 Output ripple and noise waveform

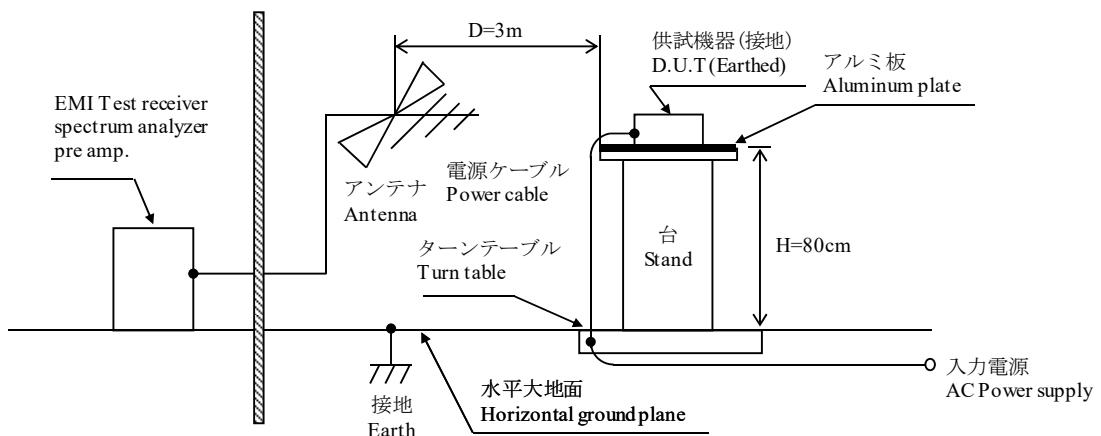


測定構成 Configuration used for determination

- EMI特性 Electro-Magnetic Interference characteristics
  - (a) 雑音端子電圧(帰還ノイズ) Conducted Emission



- (b) 雑音電界強度(放射ノイズ) Radiated Emission



## 1-2. 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	DIGITAL STORAGE OSCILLOSCOPE	LECROY	LeCroy LT345
2	DIGITAL STORAGE OSCILLOSCOPE	TEKTRONIX	TDS3014B
3	DIGITAL MULTIMETER	AGILENT	34970A
4	DIGITAL POWER METER	YOKOGAWA ELECT.	WT210
5	CURRENT PROBE	TEKTRONIX	TCP-312
6	CURRENT AMP	TEKTRONIX	TCPA-300
7	DYNAMIC DUMMY LOAD	CHROMA	Chroma 63103A
8	DYNAMIC DUMMY LOAD	KIKUSUI	PLZ150U
9	CVCF	TDK LAMBDA	TDK Lambda Z-PLUS
10	CVCF	TDK LAMBDA	TDK Lambda GEN40-38
11	CVCF	KIKUSUI	PCR1000LE
12	CVCF	CHROMA	62012P-80-60
13	CONTROLLED TEMP. CHAMBER	ESPEC	SU-261 / SU-262
14	EMI TEST RECEIVER / SPECTRUM ANALYZER	ROHDE & SCHWARZ	ESR EMI Test Receiver
15	LISN	ROHDE & SCHWARZ	ENV216
16	FREQUENCY RESPONSE ANALYZER	NF	FRA51615

## 2. 特性データ Characteristics

### 2-1. 静特性 Steady state data

#### (1) 入力・負荷・温度変動／出力起動・遮断電圧

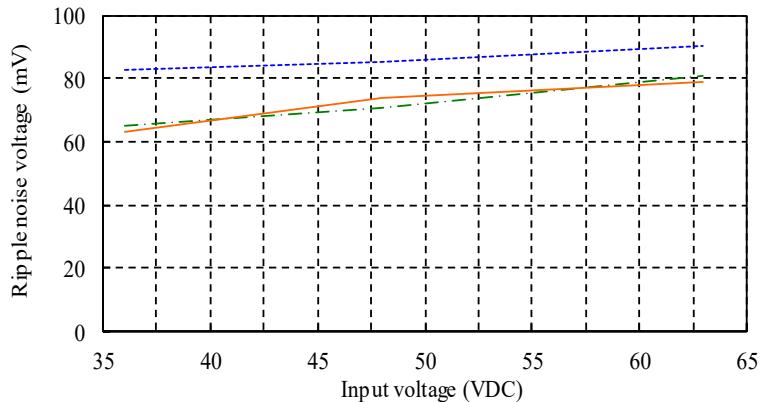
Regulation - line and load, Temperature drift / Start up voltage and Drop out voltage

5V	1. Regulation - line and load						Condition	Ta : 25 °C			
	Iout \ Vin	36VDC	48VDC	63VDC	Line regulation						
	0%	5.056V	5.056V	5.056V	0mV		0.000%				
	50%	5.038V	5.038V	5.038V	0mV		0.000%				
	100%	5.020V	5.020V	5.020V	0mV		0.000%				
	Load regulation	36mV	36mV	36mV							
		0.720%	0.720%	0.720%							
2. Temperature drift											
	Conditions						Vin : 48 VDC				
	Iout : 100 %										
	Ta	-20°C	+25°C	+50°C	Temperature stability						
	Vout	5.013V	5.020V	5.010V	10mV		0.200%				
3. Start up voltage and Drop out voltage											
	Conditions						Ta : 25 °C				
	Iout : 100 %										
	Start up voltage (Vin)	34VDC									
	Drop out voltage (Vin)	29VDC									
12V	1. Regulation - line and load						Condition	Ta : 25 °C			
	Iout \ Vin	36VDC	48VDC	63VDC	Line regulation						
	0%	11.998V	11.998V	11.998V	0mV		0.000%				
	50%	11.990V	11.990V	11.990V	0mV		0.000%				
	100%	11.983V	11.983V	11.983V	0mV		0.000%				
	Load regulation	15mV	15mV	15mV							
		0.125%	0.125%	0.125%							
2. Temperature drift											
	Conditions						Vin : 48 VDC				
	Iout : 100 %										
	Ta	-20°C	+25°C	+50°C	Temperature stability						
	Vout	11.971V	11.983V	12.007V	36mV		0.300%				
3. Start up voltage and Drop out voltage											
	Conditions						Ta : 25 °C				
	Iout : 100 %										
	Start up voltage (Vin)	34VDC									
	Drop out voltage (Vin)	29VDC									
24V	1. Regulation - line and load						Condition	Ta : 25 °C			
	Iout \ Vin	36VDC	48VDC	63VDC	Line regulation						
	0%	24.072V	24.071V	24.072V	1mV		0.004%				
	50%	24.067V	24.067V	24.067V	0mV		0.000%				
	100%	24.065V	24.064V	24.064V	1mV		0.004%				
	Load regulation	7mV	7mV	8mV							
		0.029%	0.029%	0.033%							
2. Temperature drift											
	Conditions						Vin : 48 VDC				
	Iout : 100 %										
	Ta	-20°C	+25°C	+50°C	Temperature stability						
	Vout	24.055V	24.064V	24.007V	57mV		0.237%				
3. Start up voltage and Drop out voltage											
	Conditions						Ta : 25 °C				
	Iout : 100 %										
	Start up voltage (Vin)	34VDC									
	Drop out voltage (Vin)	29VDC									

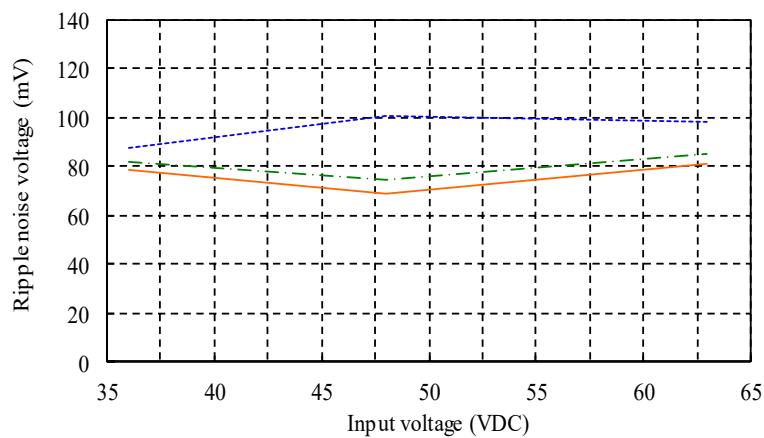
## (2) リップルノイズ電圧対入力電圧 Ripple noise voltage vs. Input voltage

Conditions      Iout : 100 %  
Ta : -20 °C    -----  
                25 °C    - - -  
                50 °C    —

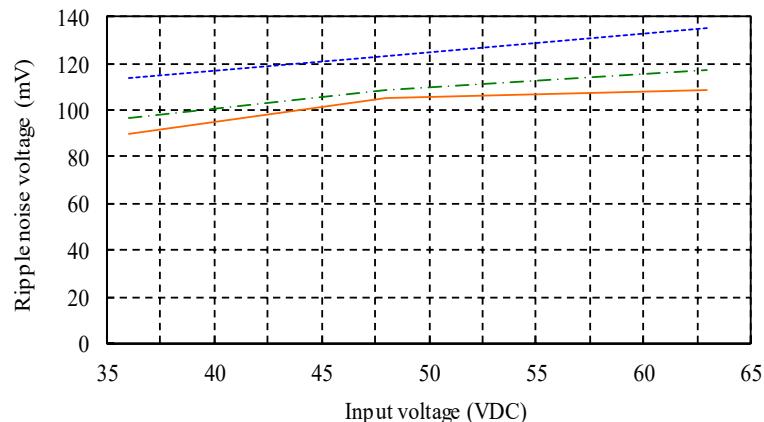
5V



12V



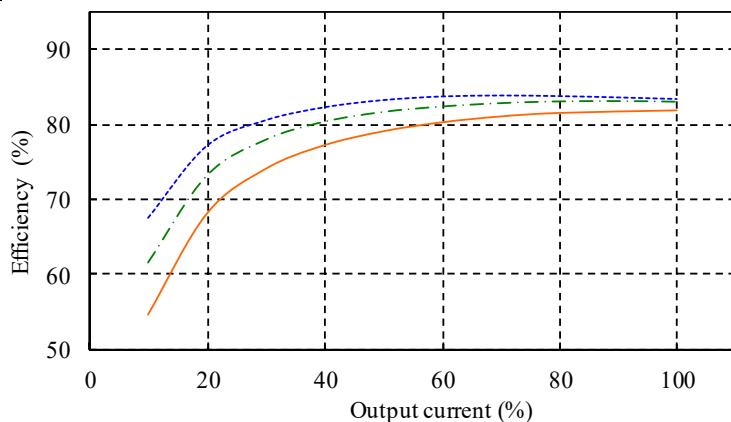
24V



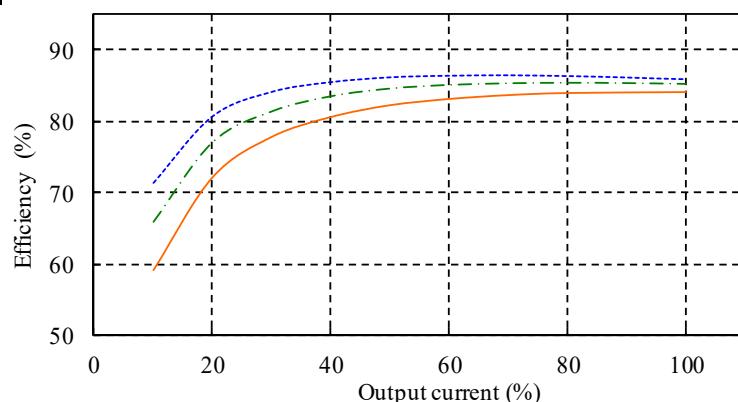
## (3) 効率対出力電流 Efficiency vs. Output current

Conditions  
Vin : 36 VDC  $\text{---}$   
48 VDC  $\text{...}$   
63 VDC  $\text{—}$   
Ta : 25 °C

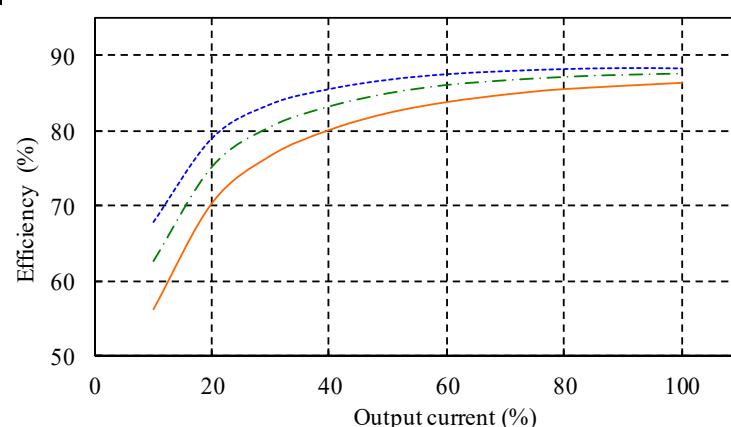
5V



12V



24V



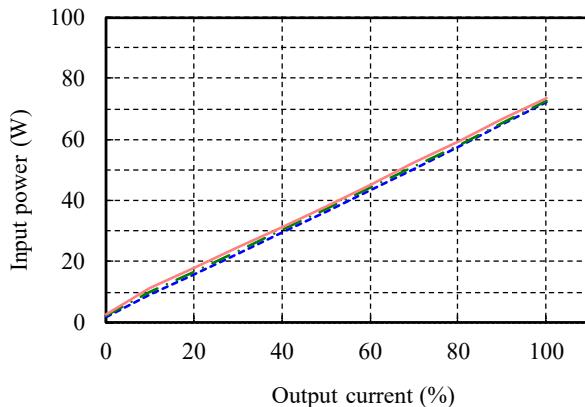
## (4) 入力電力対出力電流 Input power vs. Output current

5V

Vin	Input power (CNT ON)	
	Iout : 0%	
36VDC	1.61W	
48VDC	2.02W	
63VDC	2.74W	

Vin	Input power (CNT OFF)	
	Iout : 0%	
36VDC	0.26W	
48VDC	0.47W	
63VDC	0.82W	

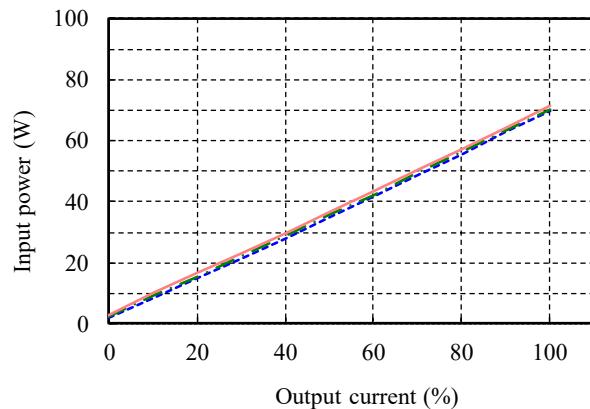
Conditions  
 Vin : 36 VDC ---  
 48 VDC ----  
 63 VDC ---  
 Ta : 25 °C



12V

Vin	Input power (CNT ON)	
	Iout : 0%	
36VDC	1.85W	
48VDC	2.29W	
63VDC	3.01W	

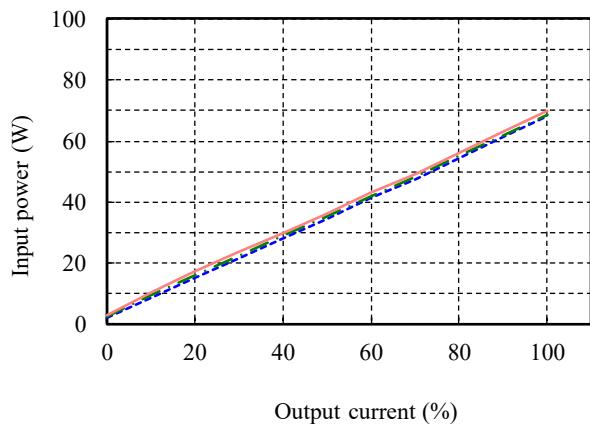
Vin	Input power (CNT OFF)	
	Iout : 0%	
36VDC	0.26W	
48VDC	0.47W	
63VDC	0.84W	



24V

Vin	Input power (CNT ON)	
	Iout : 0%	
36VDC	2.05W	
48VDC	2.40W	
63VDC	3.03W	

Vin	Input power (CNT OFF)	
	Iout : 0%	
36VDC	0.26W	
48VDC	0.47W	
63VDC	0.84W	

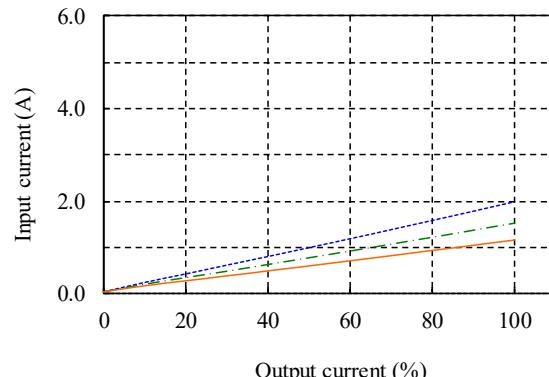


## (5) 入力電流対出力電流 Input current vs. Output current

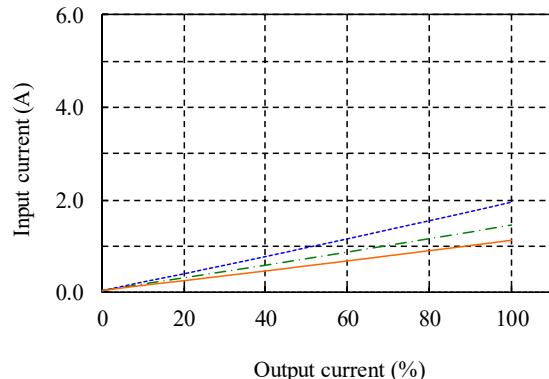
Conditions       $V_{in}$  : 36 VDC -----  
                   48 VDC ----  
                   63 VDC —  
                    $T_a$  : 25 °C

**5V**

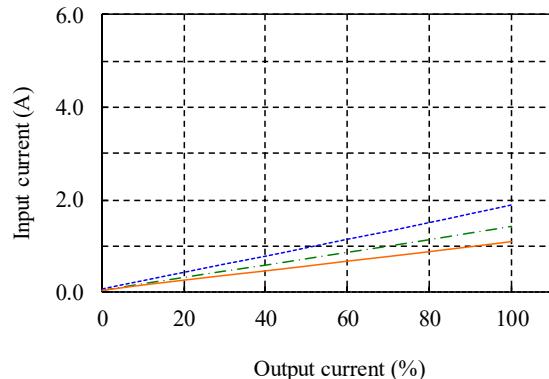
$V_{in}$	Input current	
	Iout : 0%	
36VDC	0.04A	
48VDC	0.04A	
63VDC	0.04A	


**12V**

$V_{in}$	Input current	
	Iout : 0%	
36VDC	0.05A	
48VDC	0.05A	
63VDC	0.05A	


**24V**

$V_{in}$	Input current	
	Iout : 0%	
36VDC	0.06A	
48VDC	0.05A	
63VDC	0.05A	

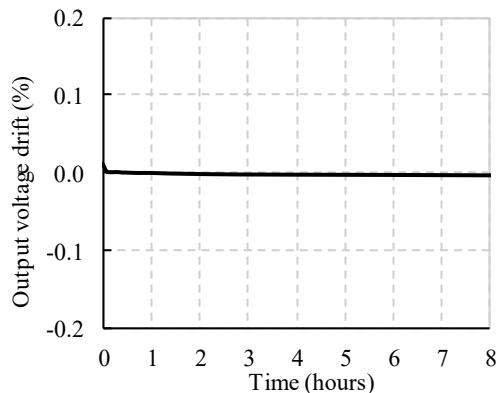


2-2. 通電ドリフト特性

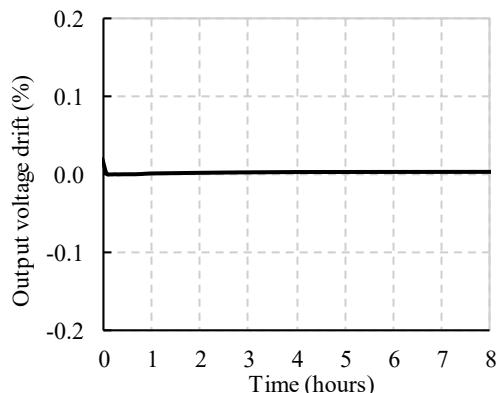
Warm up voltage drift characteristics

Conditions Vin : 48 VDC  
Iout : 100 %  
Ta : 25 °C

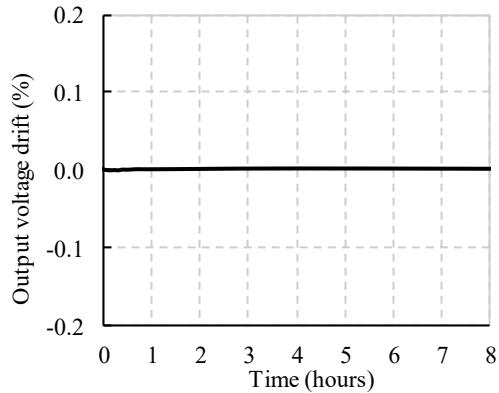
5V



12V



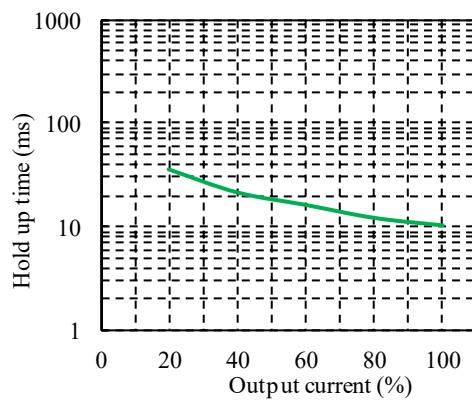
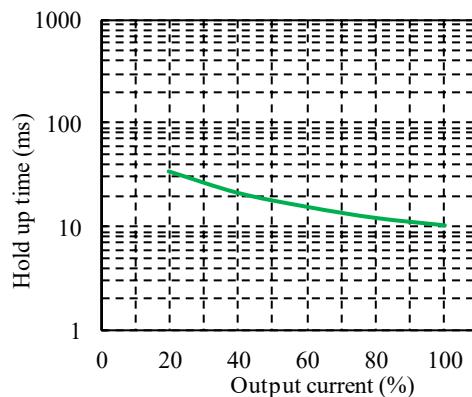
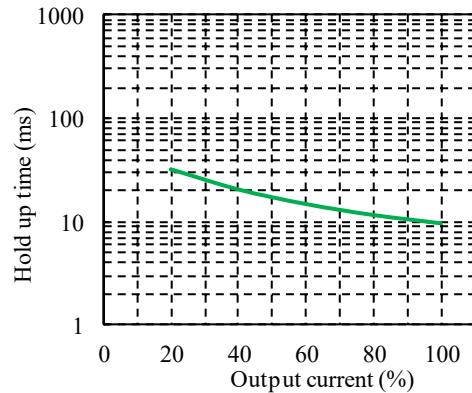
24V



2-3. 出力保持時間特性

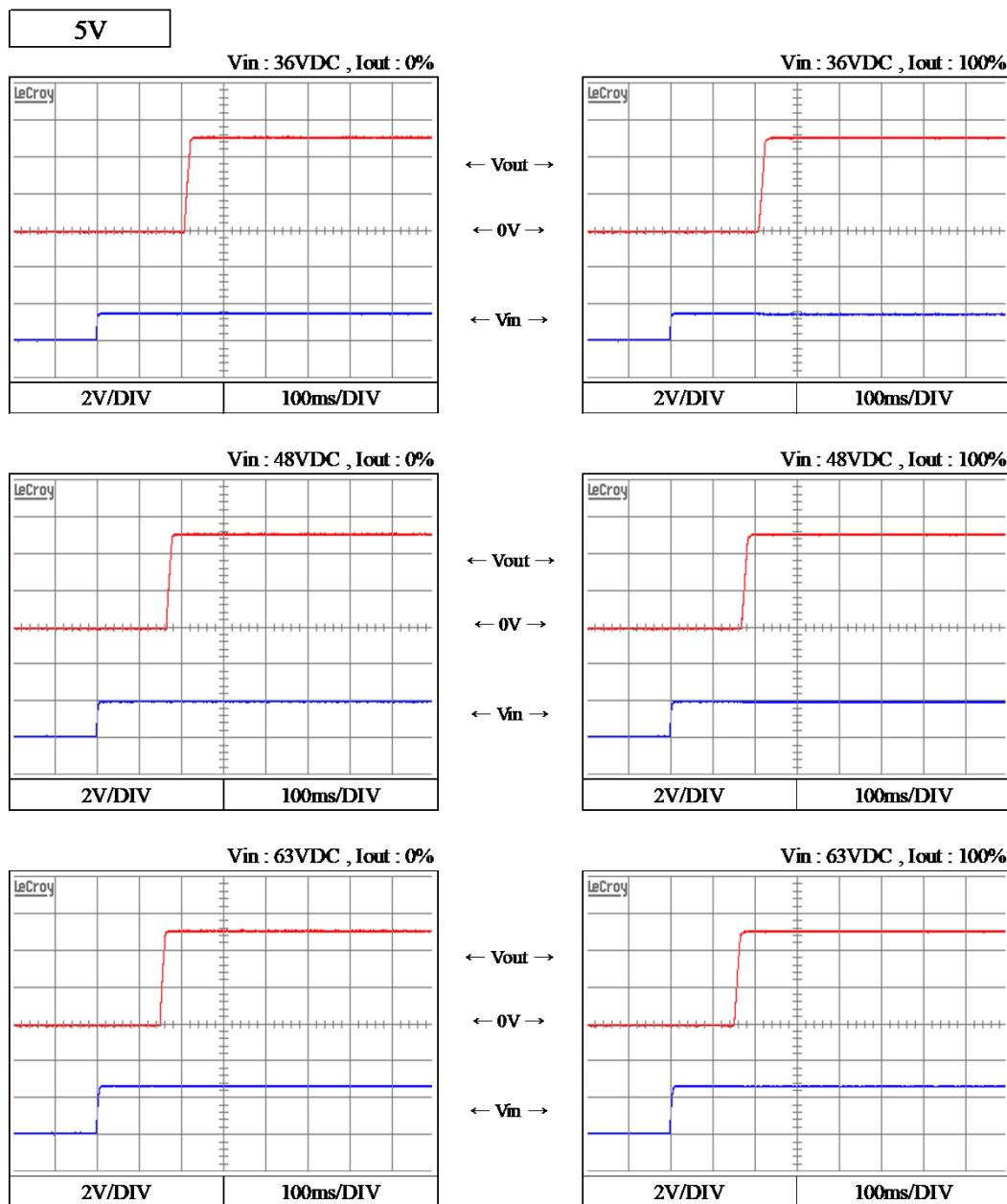
Hold up time characteristics

Conditions Vin : 48 VDC  
Ta : 25 °C



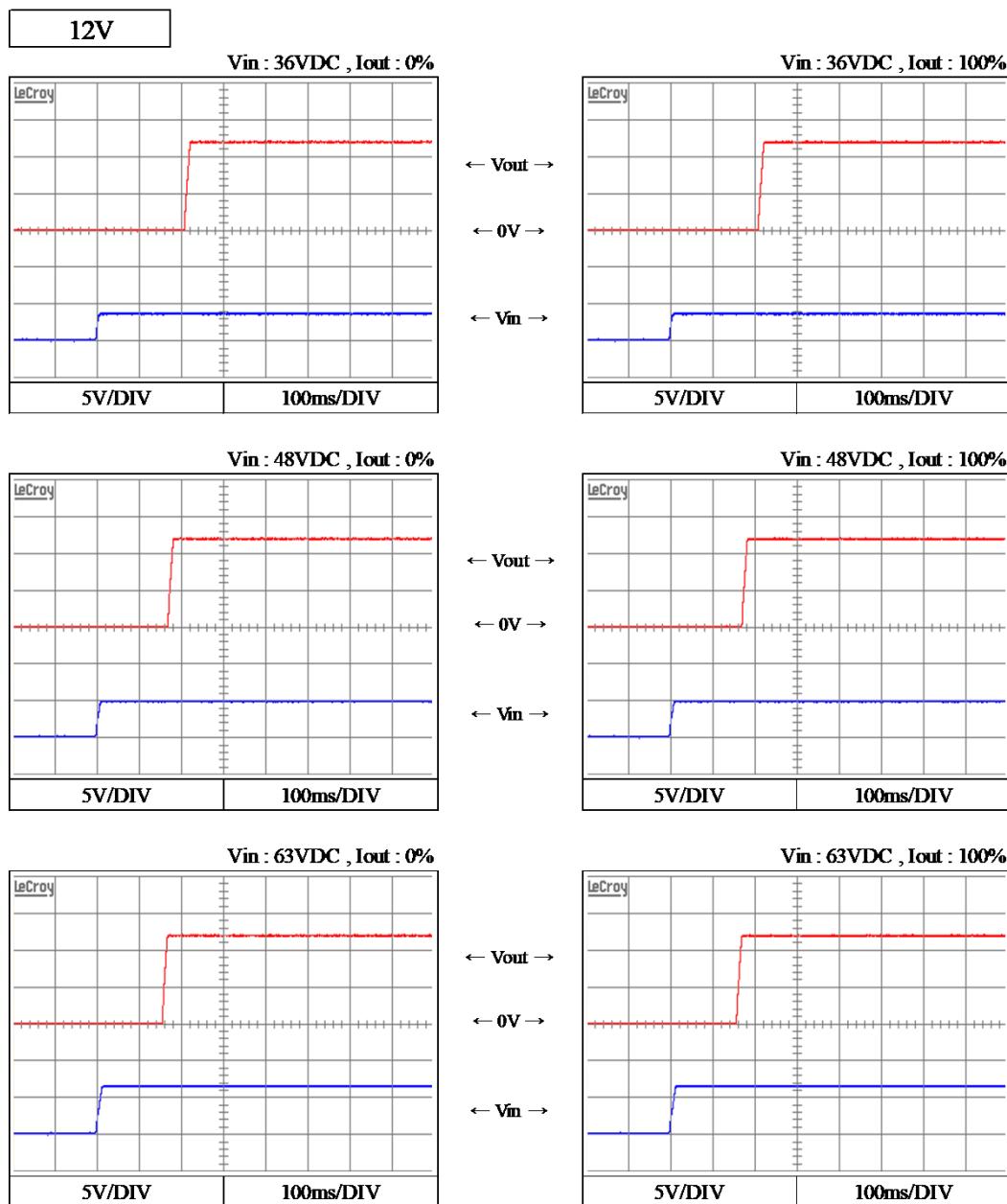
## 2-4. 出力立ち上がり特性 Output rise characteristics

Condition Ta : 25 °C



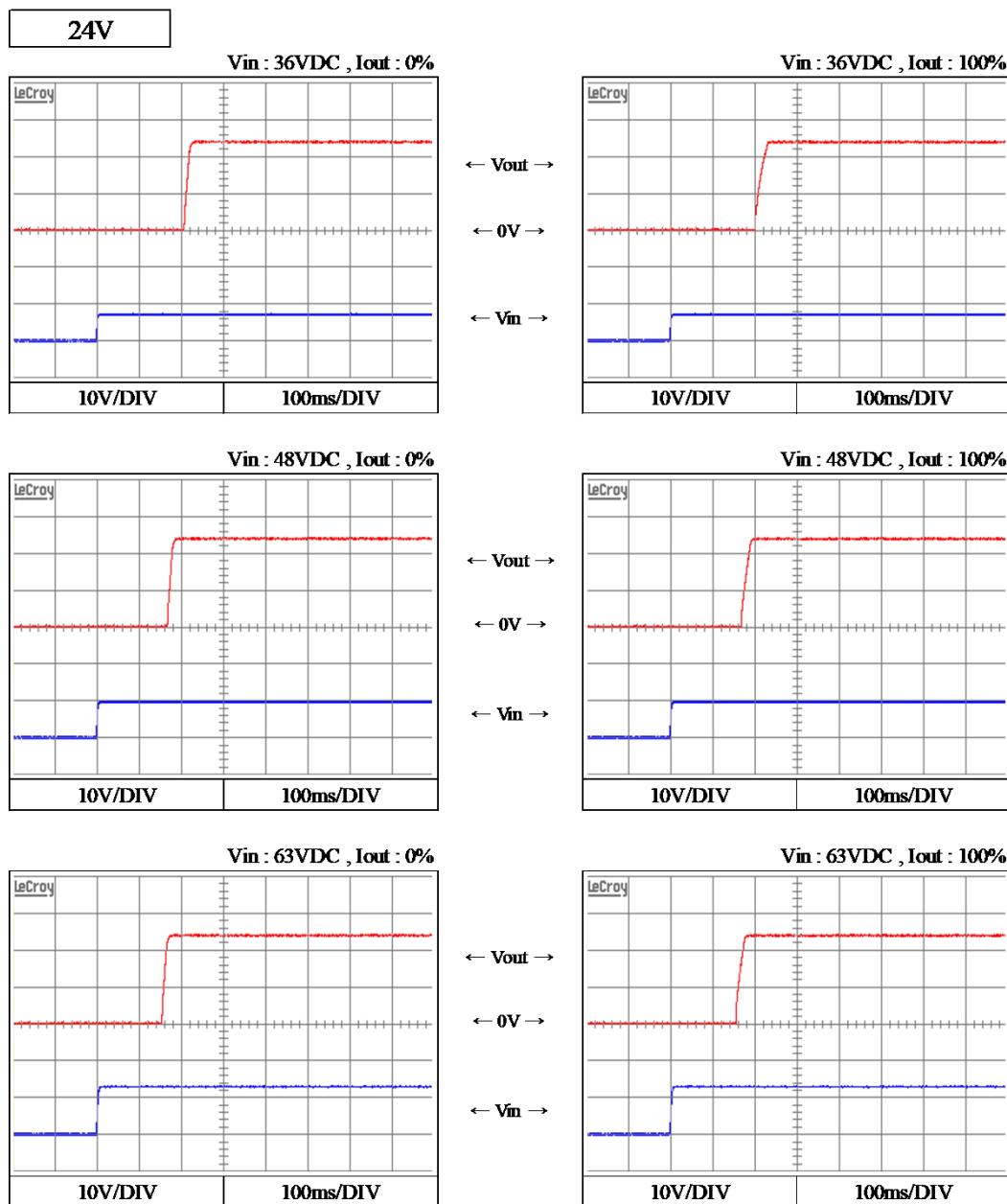
## 2-4. 出力立ち上がり特性 Output rise characteristics

Condition Ta : 25 °C



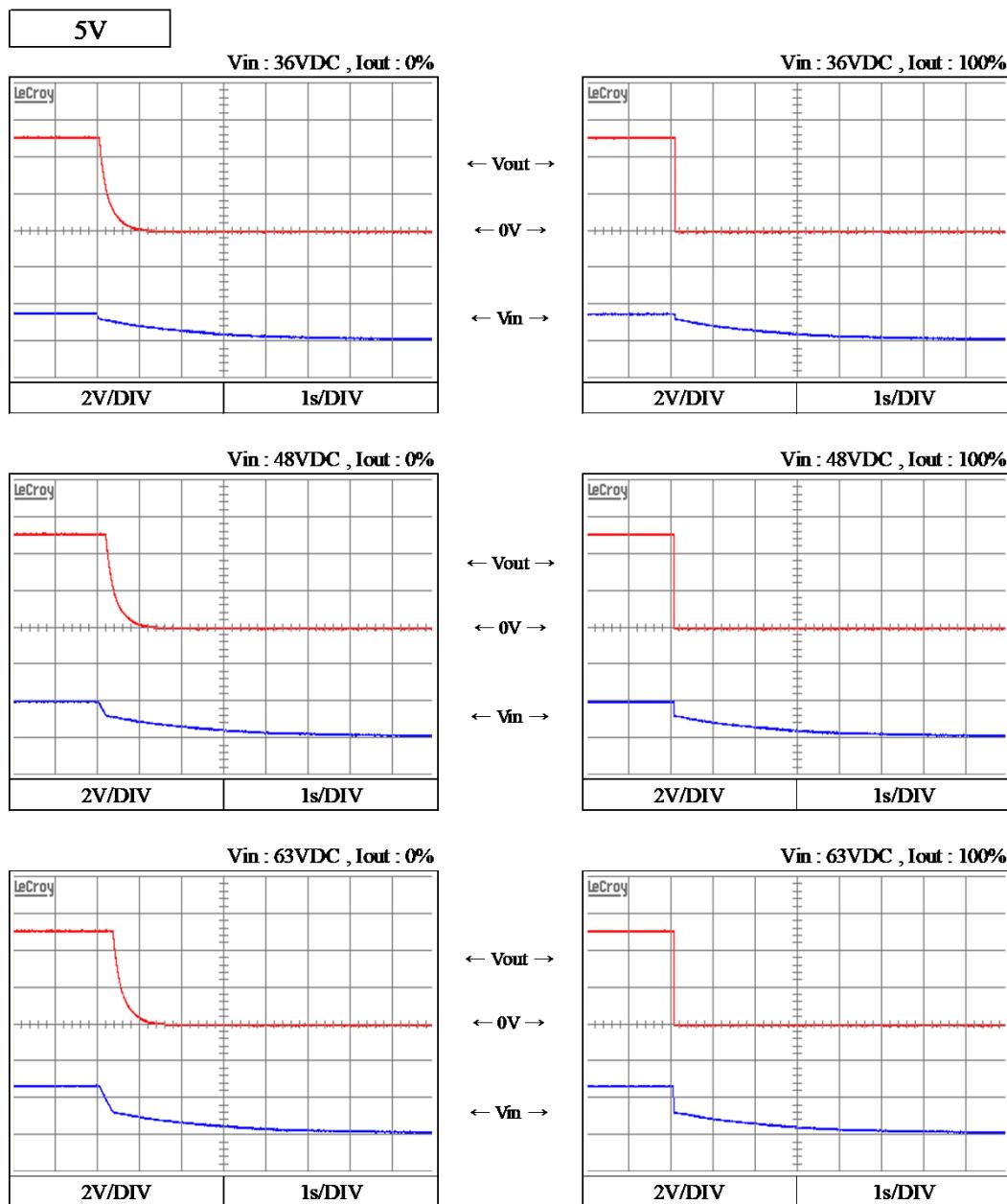
## 2-4. 出力立ち上がり特性 Output rise characteristics

Condition Ta : 25 °C



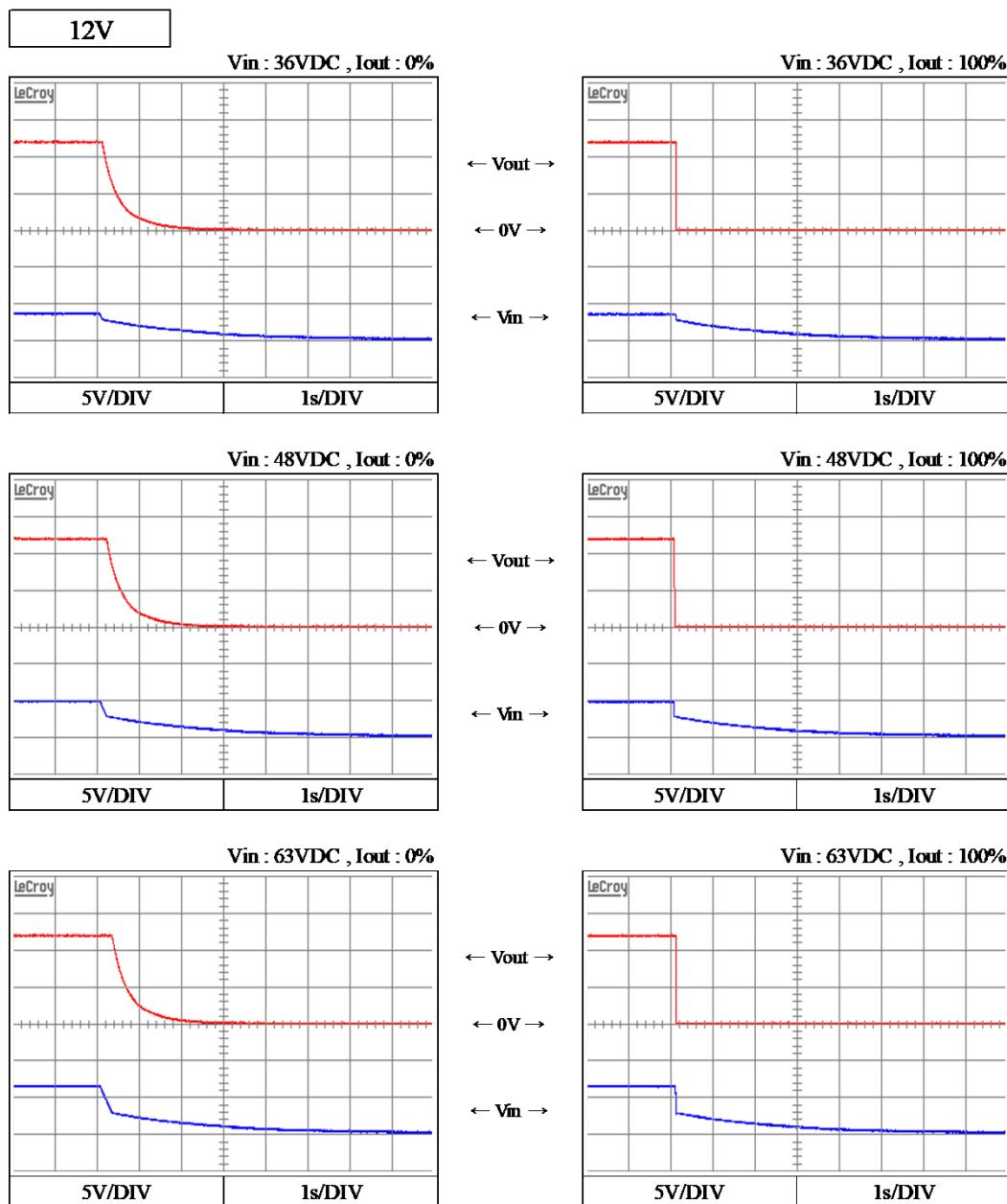
## 2-5. 出力立ち下がり特性 Output fall characteristics

Condition Ta : 25 °C



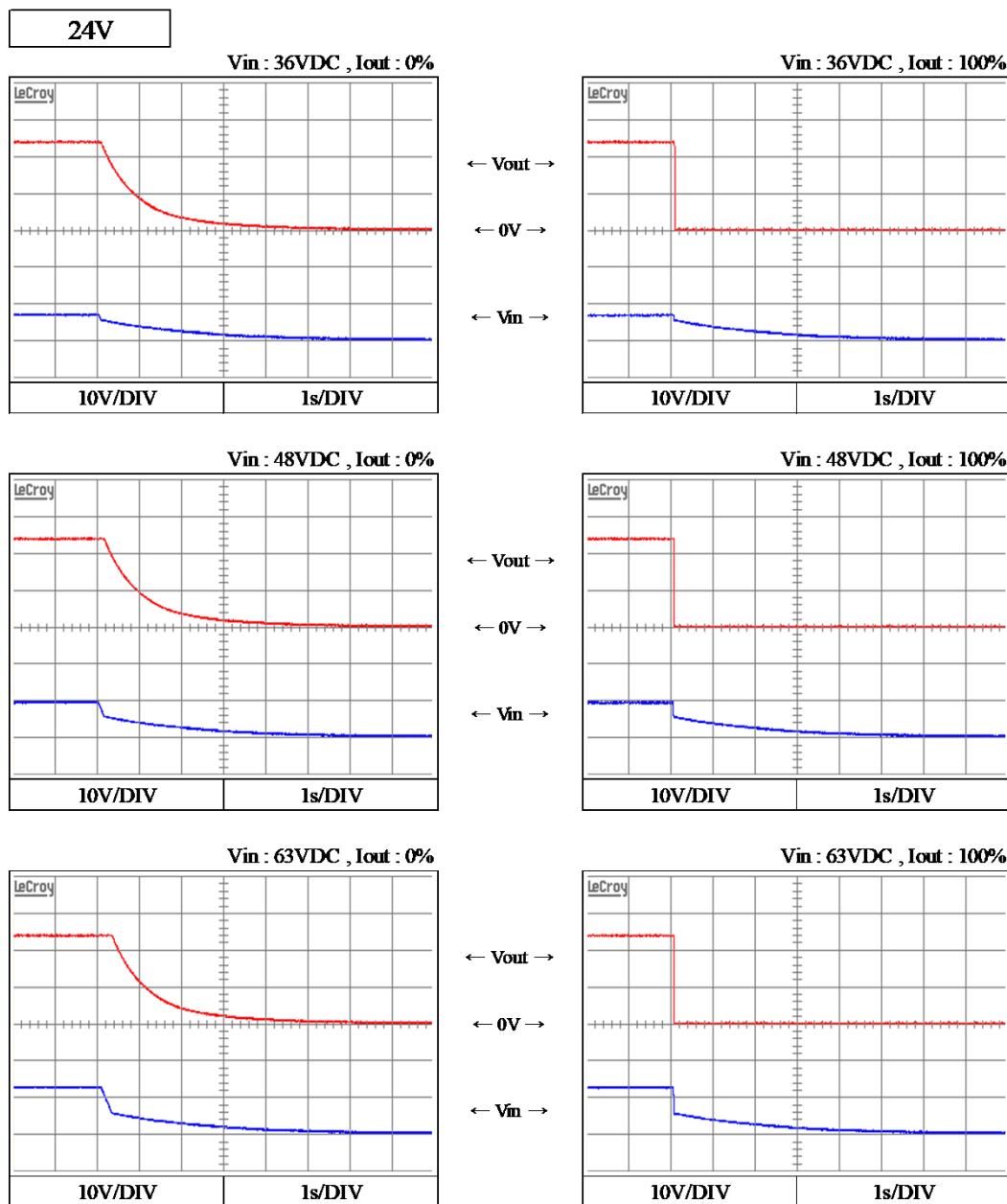
## 2-5. 出力立ち下がり特性 Output fall characteristics

Condition Ta : 25 °C



## 2-5. 出力立ち下がり特性 Output fall characteristics

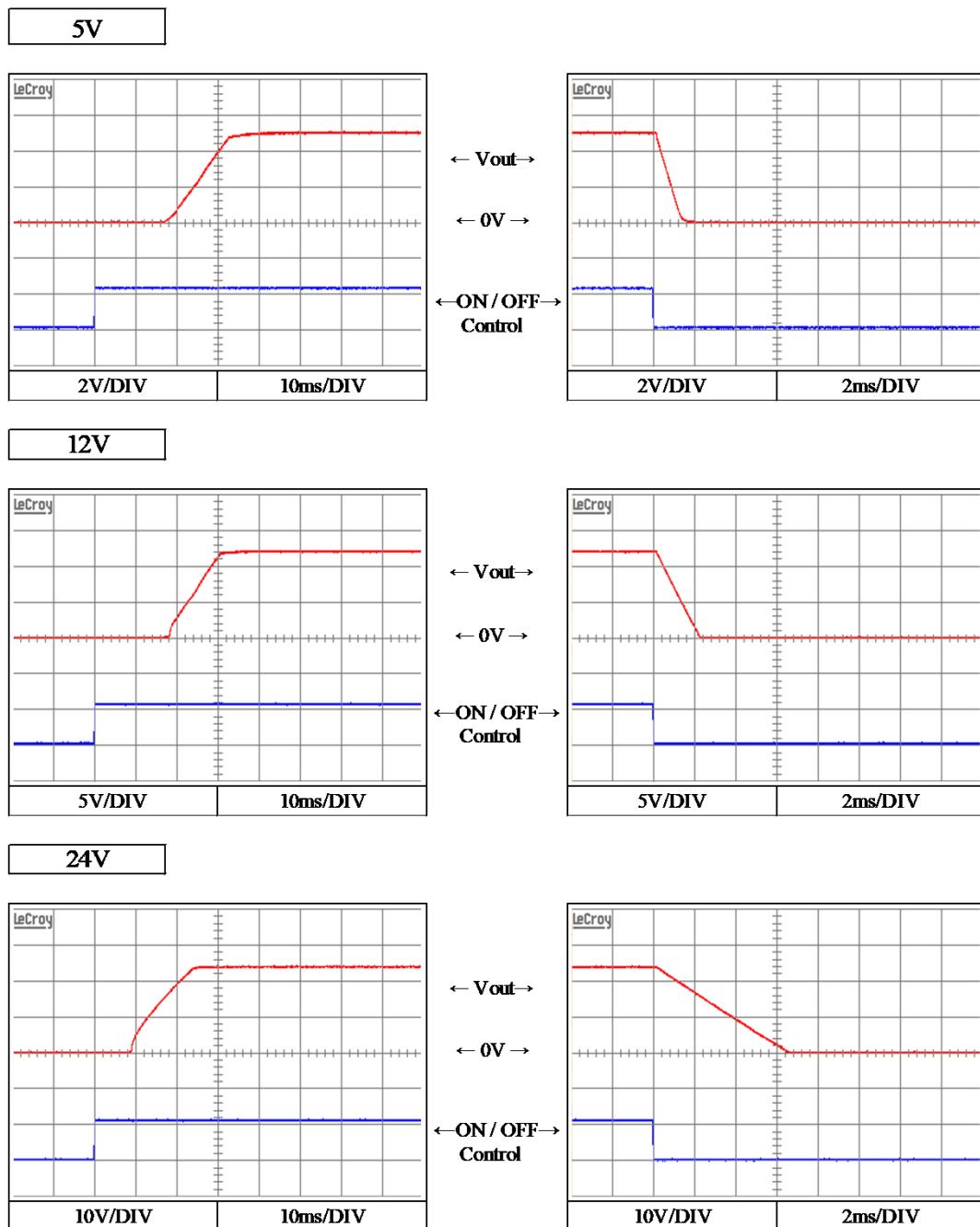
Condition Ta : 25 °C



## 2-6. ON/OFFコントロール時出力立ち上がり、立下がり特性

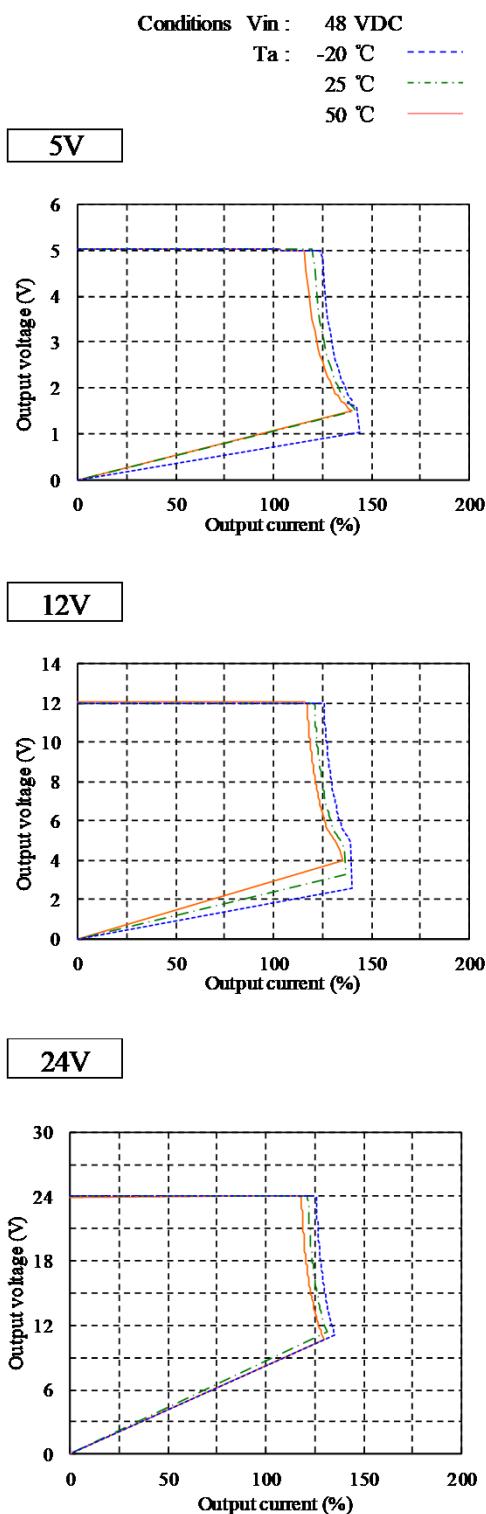
Output rise, fall characteristics with ON/OFF RC Control

Conditions Vin : 48 VDC  
Iout : 100 %  
Ta : 25 °C



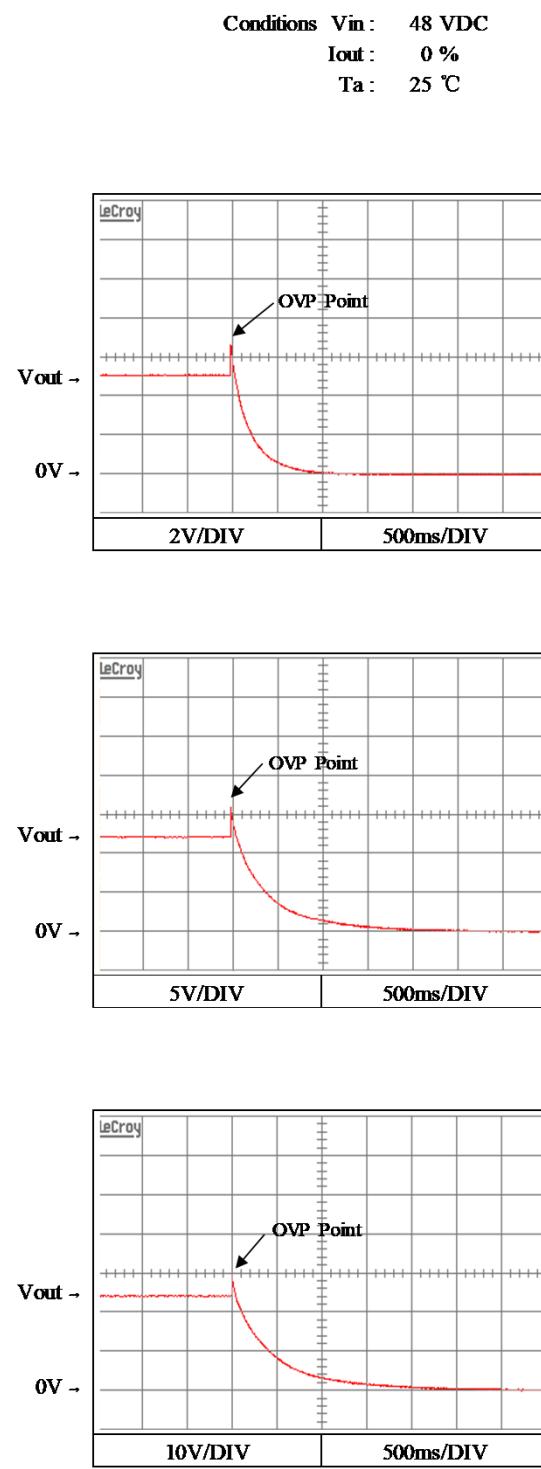
## 2-7. 過電流保護特性

Over current protection (OCP) characteristics



## 2-8. 過電壓保護特性

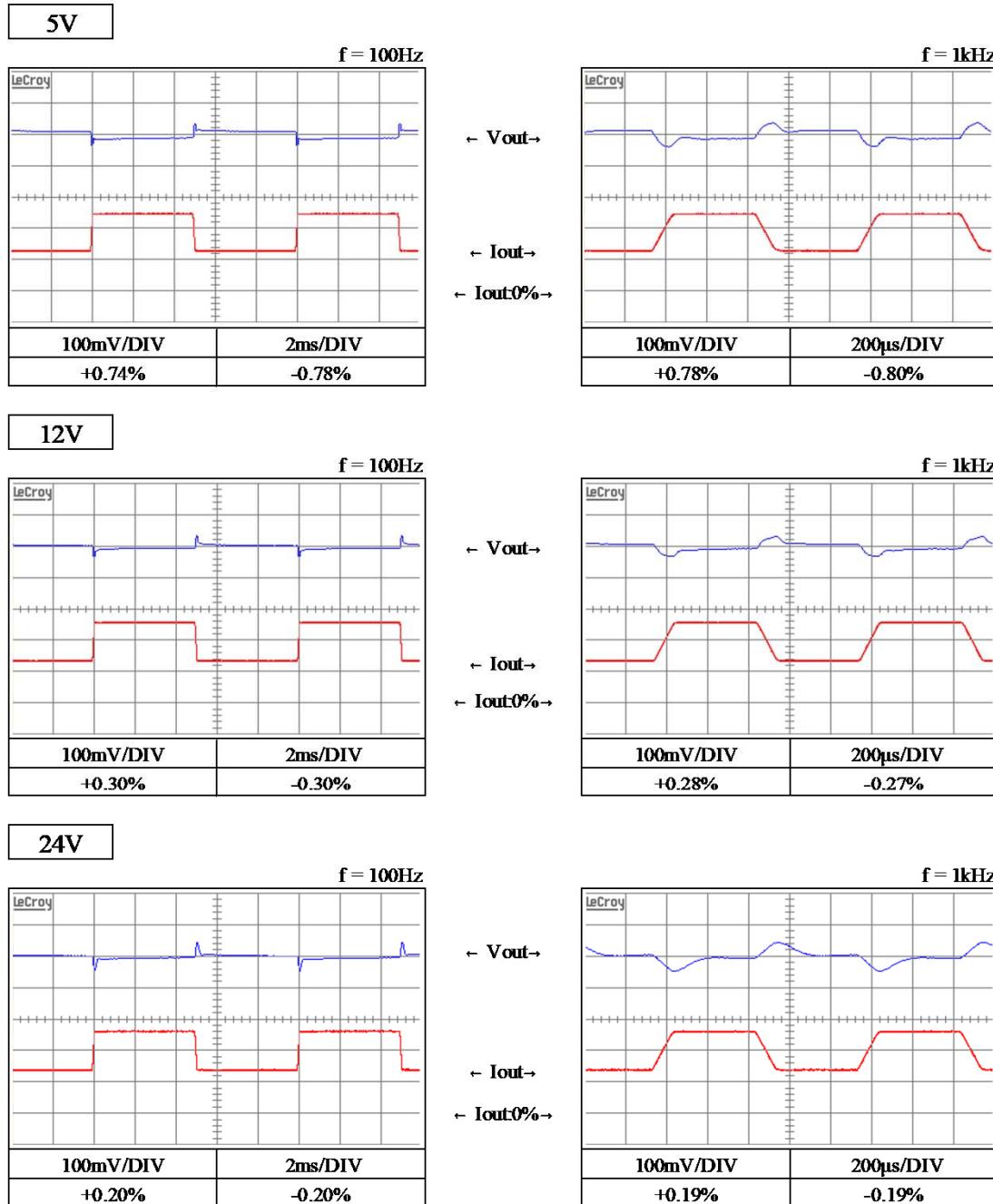
Over voltage protection (OVP) characteristics



## 2-9. 過渡応答(負荷急変)特性 Dynamic load response characteristics

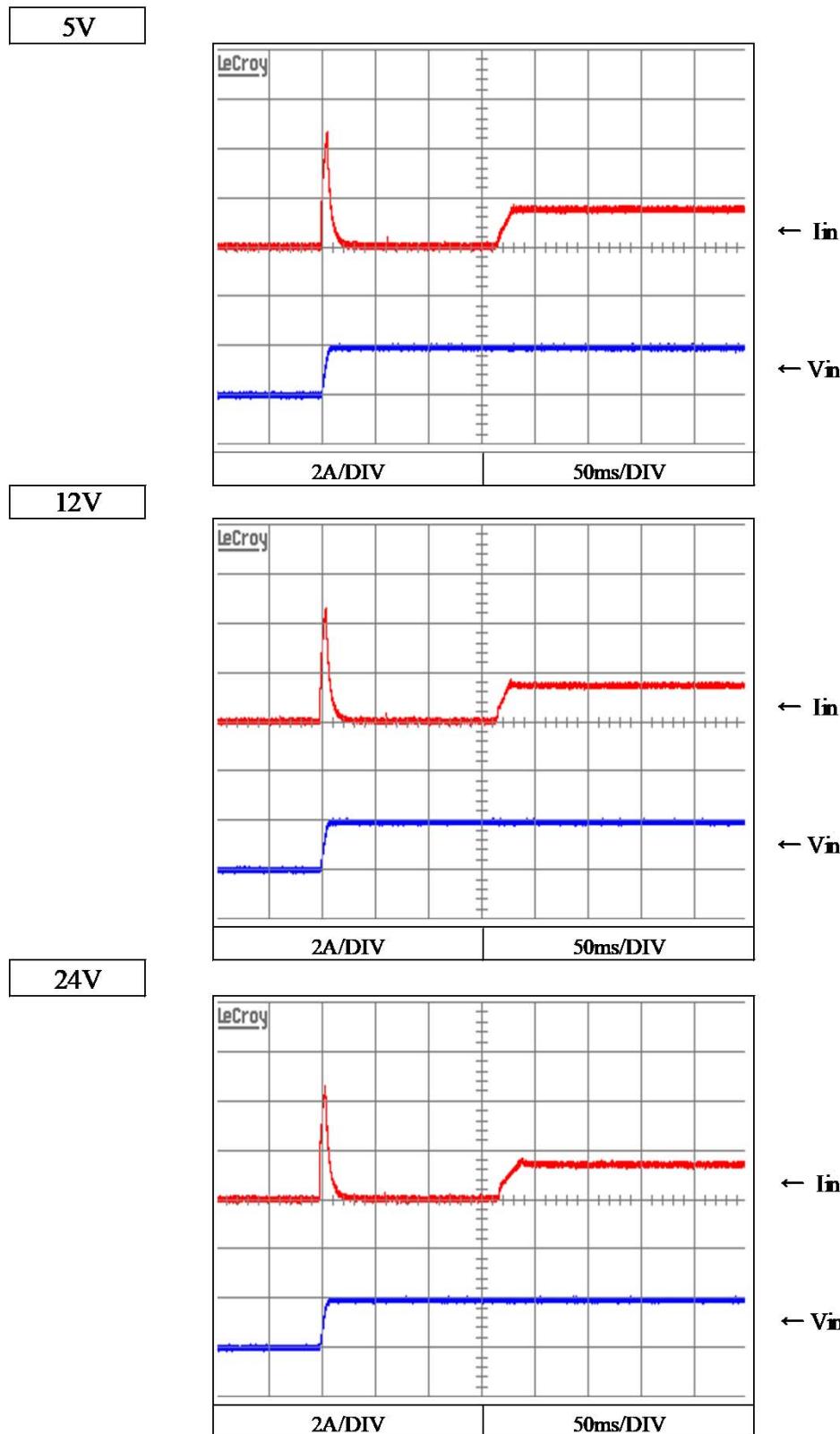
**Conditions**

Vin :	48 VDC
Iout :	50 % ⇔ 100 % ( $t_r = t_f = 100\mu s$ )
Ta :	25 °C



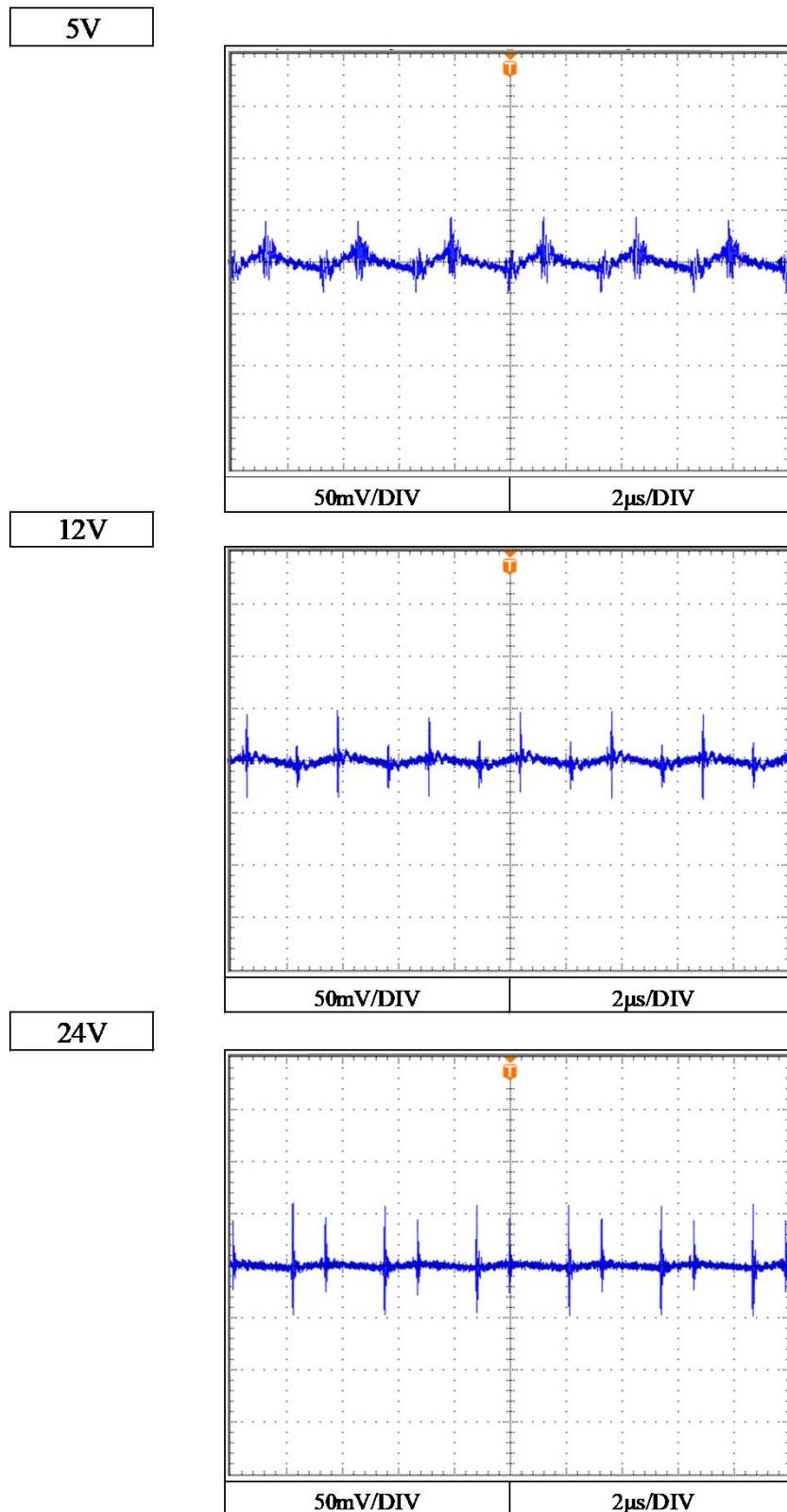
## 2-10. 入力サージ電流(突入電流)波形 Inrush current waveform

Conditions    Vin : 48 VDC  
                 Iout : 100 %  
                 Ta : 25 °C



## 2-11. 出力リップル、ノイズ波形 Output ripple and noise waveform

Conditions    Vin : 48 VDC  
                 Iout : 100 %  
                 Ta : 25 °C



## 2-12. EMI特性 Electro-Magnetic Interference characteristics

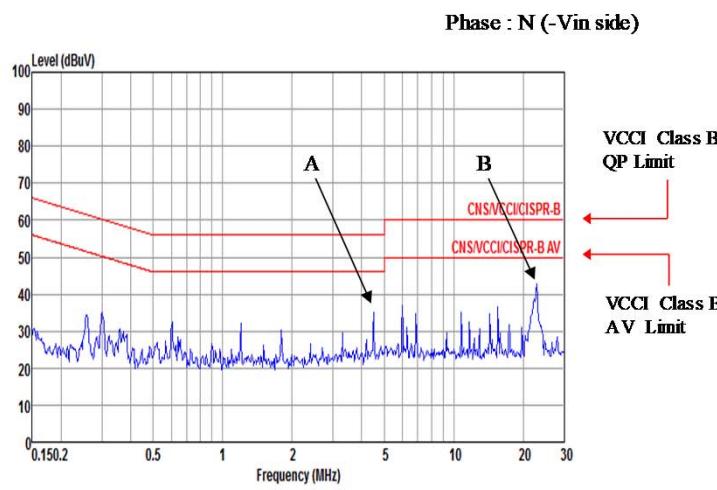
Conditions Vin : 48 VDC  
Iout : 100 %  
Ta : 25 °C

雜音端子電圧  
Conducted Emission

5V

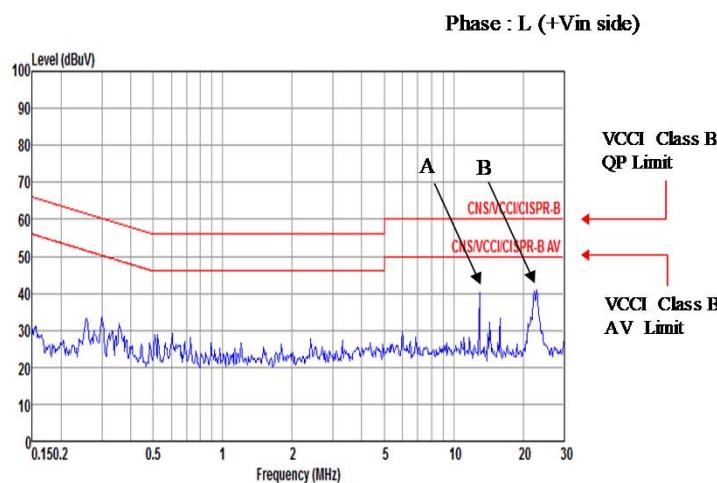
Point A (4.51MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	56.0	36.6
AV	46.0	36.7

Point B (22.46MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	40.6
AV	50.0	37.5



Point A (12.94MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	37.9
AV	50.0	37.7

Point B (22.97MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	38.6
AV	50.0	34.7



EN55011-B,EN55032-B,FCC-Bの限界値はVCCI class Bの限界値と同じ

Limit of EN55011-B,EN55032-B,FCC-B are same as its VCCI class B.

表示はピーク値

Indication is peak values.

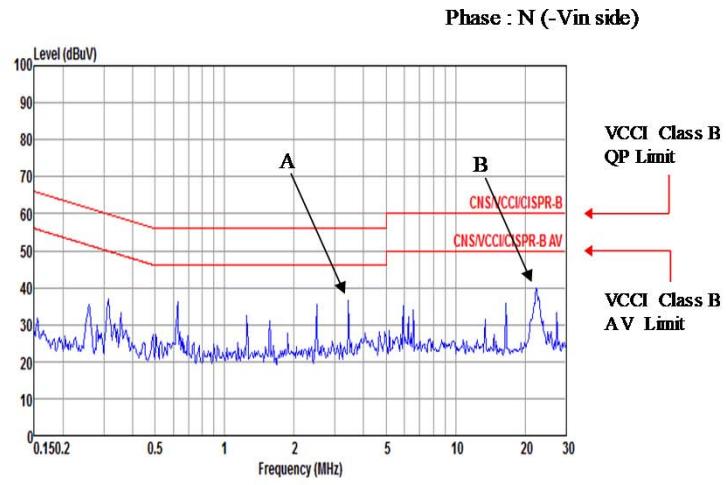
Conditions Vin : 48 VDC  
Iout : 100 %  
Ta : 25 °C

雜音端子電圧  
Conducted Emission

12V

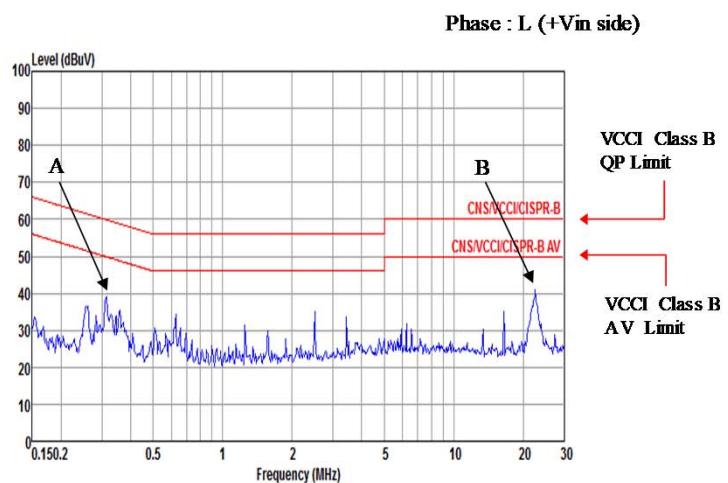
Point A (3.44MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	56.0	34.60
AV	46.0	34.67

Point B (22.55MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	42.7
AV	50.0	38.3



Point A (0.31MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	56.0	38.8
AV	56.0	44.5

Point B (22.55MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	42.8
AV	50.0	38.5



EN55011-B, EN55032-B, FCC-Bの限界値はVCCI class Bの限界値と同じ

Limit of EN55011-B, EN55032-B, FCC-B are same as its VCCI class B.

表示はピーク値

Indication is peak values.

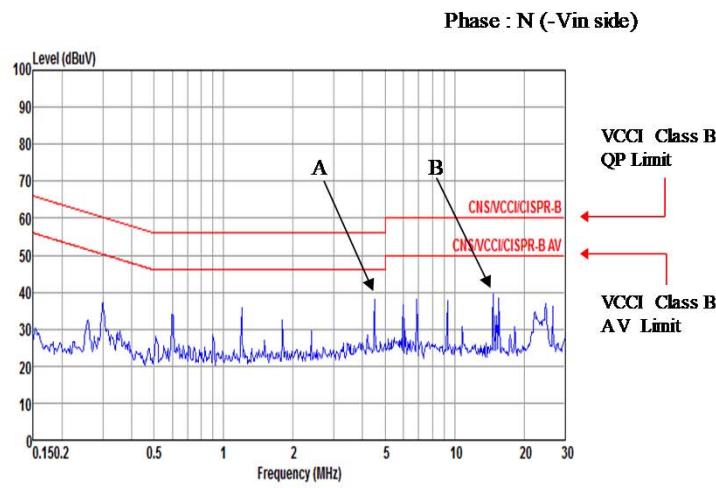
Conditions Vin : 48 VDC  
Iout : 100 %  
Ta : 25 °C

雜音端子電圧  
Conducted Emission

24V

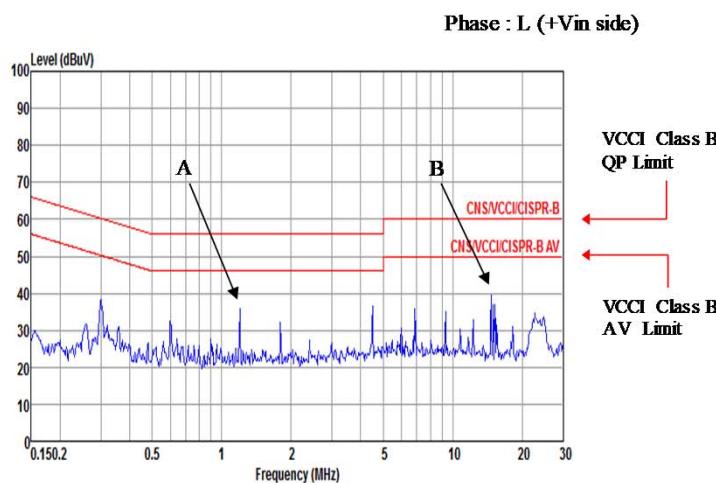
Point A (4.51MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	56.0	37.0
AV	46.0	37.1

Point B (14.73MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	37.8
AV	50.0	37.4



Point A (1.2MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	56.0	34.6
AV	46.0	34.6

Point B (14.73MHz)		
Ref. Data	Limit (dB)	Measure (dB)
QP	60.0	38.1
AV	50.0	37.2



EN55011-B, EN55032-B, FCC-Bの限界値はVCCI class Bの限界値と同じ

Limit of EN55011-B, EN55032-B, FCC-B are same as its VCCI class B.

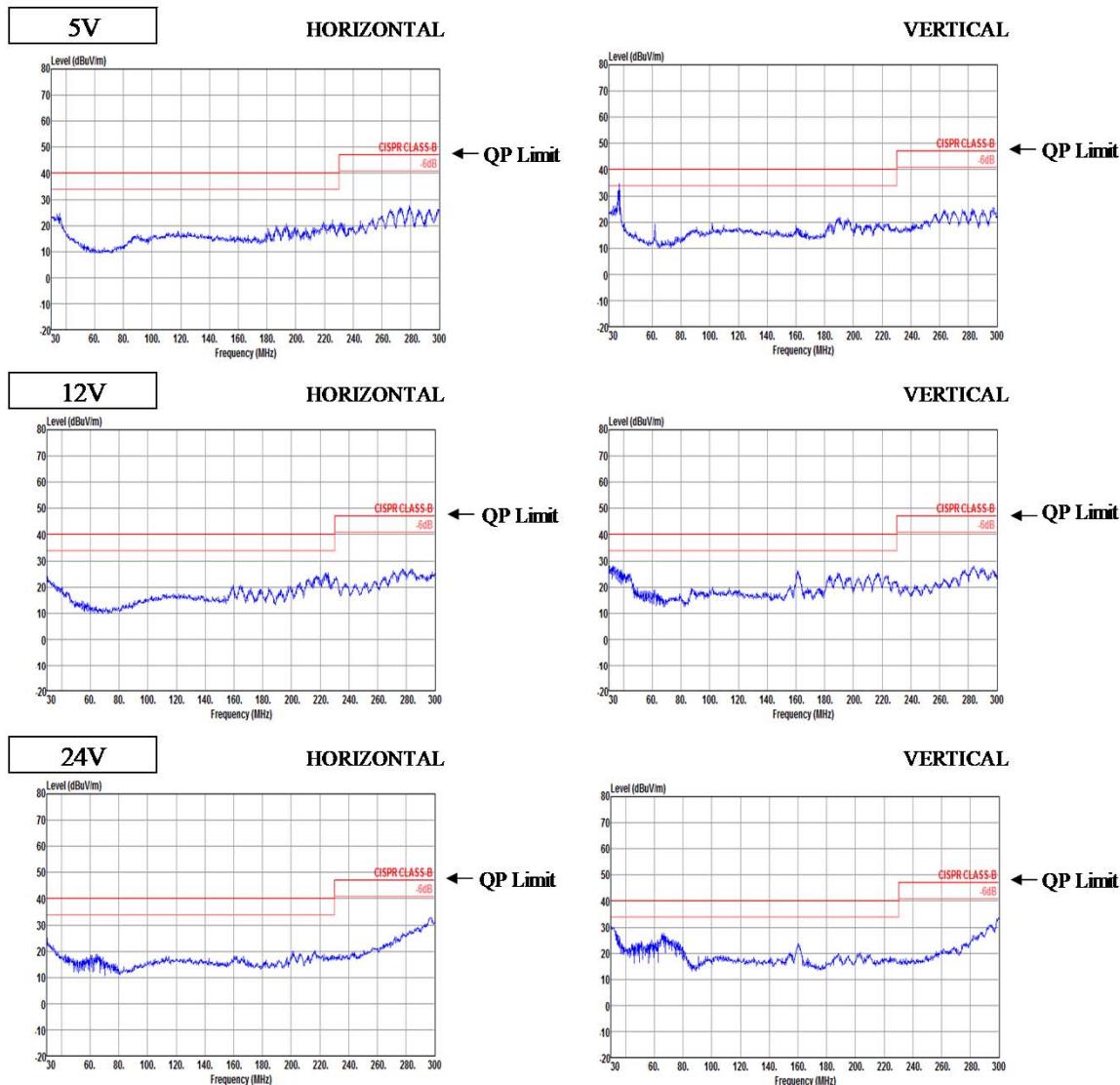
表示はピーク値

Indication is peak values.

**Conditions**

Vin :	48 VDC
Iout :	100 %
Ta :	25 °C

雜音電界強度  
Radiated Emission



EN55011-B,EN55032-Bの限界値はVCCI class Bの限界値と同じ

Limit of EN55011-B,EN55032-B are same as its VCCI class B.

表示はピーク値

Indication is peak values.